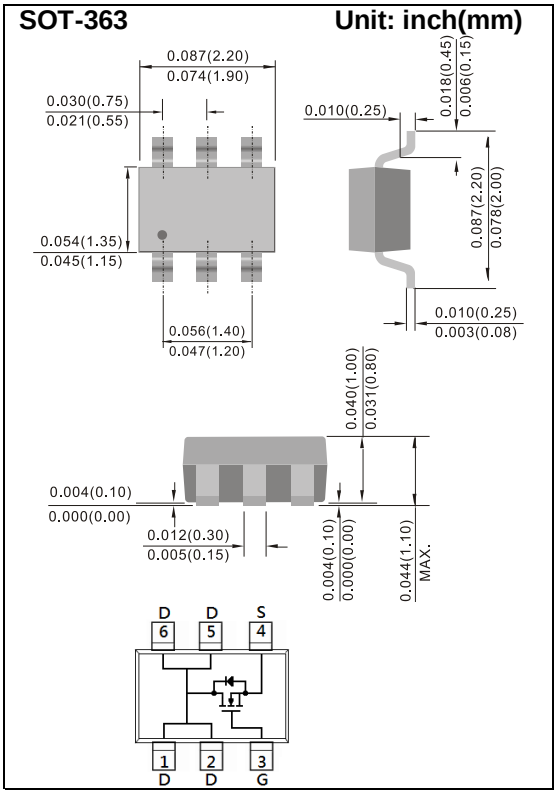
PJT7413

20V P-Channel Enhancement Mode MOSFET – ESD Protected

Voltage	-20 V	Current	-2.5A



Features

- RDS(ON) , VGS@-4.5V, ID@-2.5A<85mΩ
- RDS(ON) , VGS@-2.5V, ID@-1.8A<115mΩ
- RDS(ON) , VGS@-1.8V, ID@-1.3A<150mΩ
- RDS(ON) , VGS@-1.5V, ID@-0.5A<250mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-363 Package
- Terminals: Solderable per MIL-STD-750, Method 2026

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	±12	V
Continuous Drain Current		I_D	-2.5	A
Pulsed Drain Current (Note 4)		I_{DM}	-10	A
Power Dissipation	T_a=25°C	P_D	750	mW
	Derate above 25°C		6	mW/°C
Operating Junction and Storage Temperature Range		T_J,T_{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient (Note 3)		$R_{\theta JA}$	167	°C/W

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=-250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=-250uA	-0.4	-0.65	-1.2	V
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=-4.5V, I_D=-2.5A	-	76	85	mΩ
		V_{GS}=-2.5V, I_D=-1.8A	-	92	115	
		V_{GS}=-1.8V, I_D=-1.3A	-	116	150	
		V_{GS}=-1.5V, I_D=-0.5A	-	160	250	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=-20V, V_{GS}=0V	-	-0.01	-1	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±12V, V_{DS}=0V	-	±10	±100	nA
Dynamic(Note 5)						
Total Gate Charge	Q_g	V_{DS}=-10V, I_D=-2.2A, V_{GS}=-4.5V (Note 1,2)	-	7	-	nC
Gate-Source Charge	Q_{gs}		-	1	-	
Gate-Drain Charge	Q_{gd}		-	1.8	-	
Input Capacitance	Ciss	V_{DS}=-10V, V_{GS}=0V, f=1.0MHZ	-	522	-	pF
Output Capacitance	Coss		-	55	-	
Reverse Transfer Capacitance	Crss		-	40	-	
Turn-On Delay Time	$td_{(on)}$	V_{DD}=-10V, I_D=-2.2A, V_{GS}=-4.5V, R_G=6Ω (Note 1,2)	-	10	-	ns
Turn-On Rise Time	tr		-	4	-	
Turn-Off Delay Time	$td_{(off)}$		-	34	-	
Turn-Off Fall Time	tf		-	5	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	-1.0	A
Diode Forward Voltage	V_{SD}	I_S=-1.0A, V_{GS}=0V	-	-0.77	-1.2	V

NOTES :

1. Pulse width≤300us, Duty cycle≤2%
2. Essentially independent of operating temperature typical characteristics.
3. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing

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TYPICAL CHARACTERISTIC CURVES

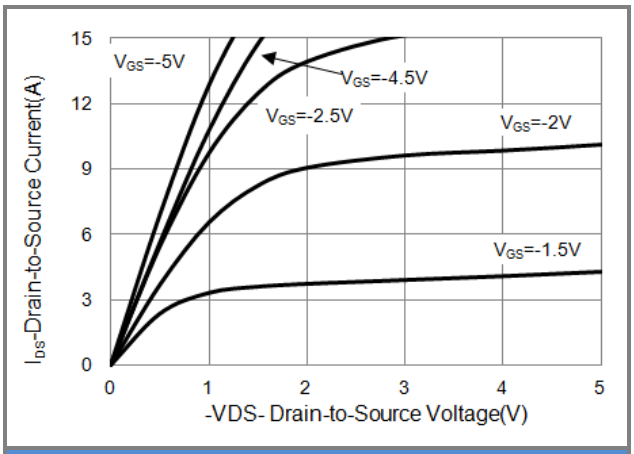

Fig.1 On-Region Characteristics

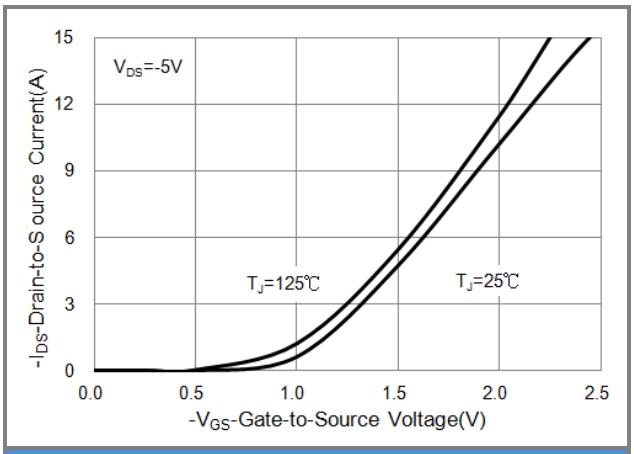

Fig.2 Transfer Characteristics

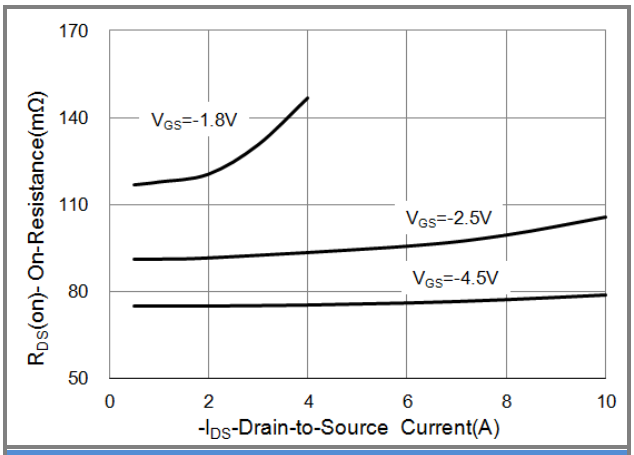

Fig.3 On-Resistance vs. Drain Current

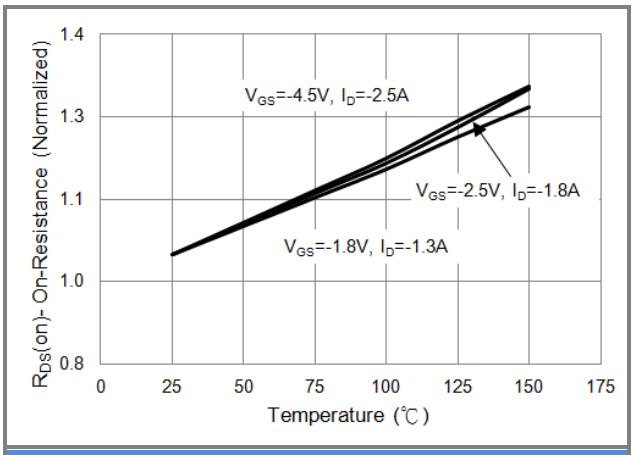

Fig.4 On-Resistance vs. Junction temperature

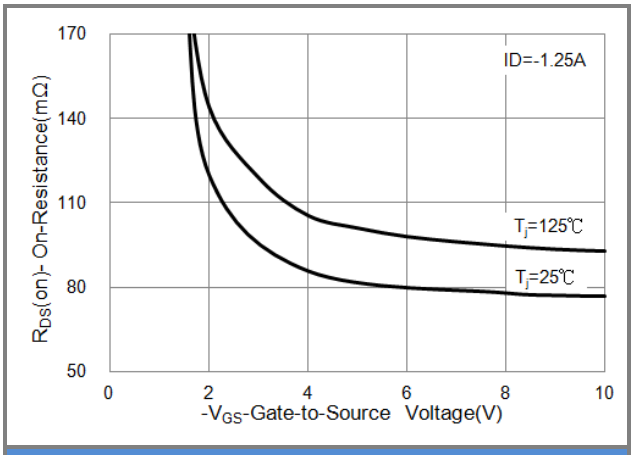

Fig.5 On-Resistance Variation with VGS.

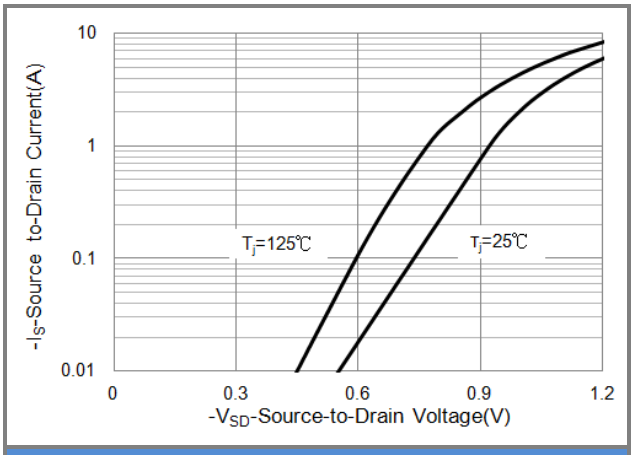

Fig.6 Body Diode Characteristics

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TYPICAL CHARACTERISTIC CURVES

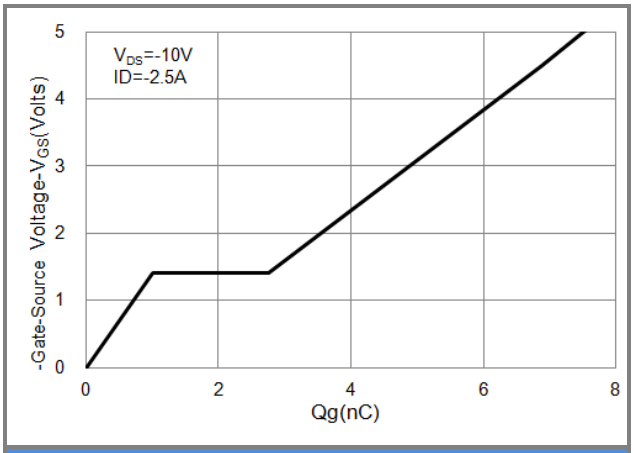

Fig.7 Gate-Charge Characteristics

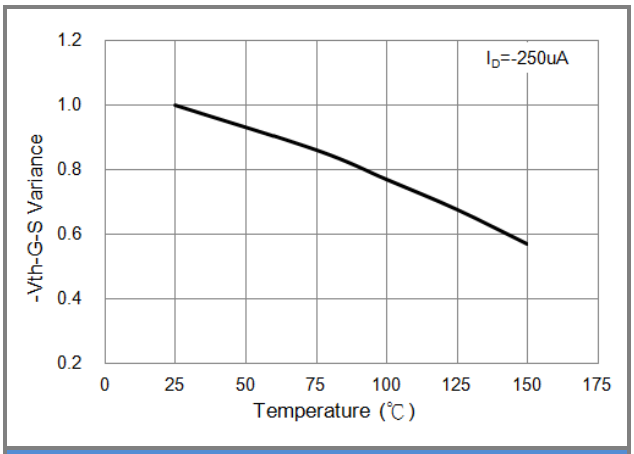

Fig.8 Threshold Voltage Variation with Temperature.

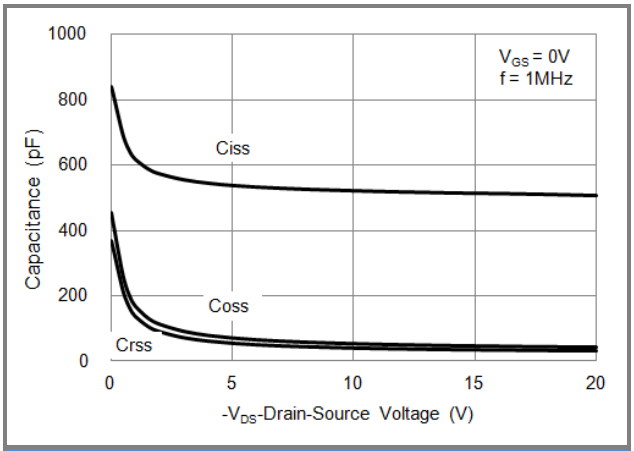

Fig.9 Capacitance vs. Drain-Source Voltage.

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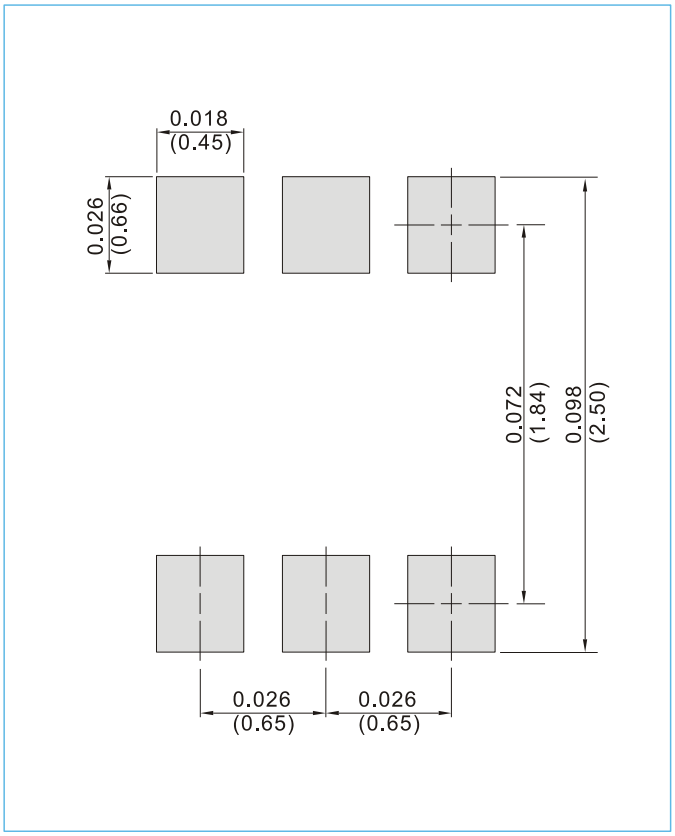
PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJT7413_S1_00001	SOT-363	3K pcs / 7” reel	T13	Halogen free
PJT7413_S2_00001	SOT-363	10K pcs / 13” reel	T13	Halogen free

MOUNTING PAD LAYOUT

SOT-363 Unit : inch(mm)



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